

IN THE CLAIMS:

Please amend the claims as follows:

1. (Currently amended) A reflection type liquid crystal display, comprising:

C2 a pair of substrates disposed opposite to each other with a liquid crystal layer disposed therebetween;

a plurality of switching elements formed on one surface of at least one of said pair of substrates;

a reflective layer constituted of a same material as a material constituting an electrode of said plurality of switching elements and simultaneously formed during formation of said electrode of said plurality of switching elements on a same plane as a plane of said electrode; and

a transparent pixel electrode formed on said reflective layer via an insulation layer and connected to at least one electrode included in at least one of said plurality of switching elements.

2. (Currently amended) The reflection type liquid crystal display according to claim 1, wherein

said plurality of switching elements includes at least a thin film transistor, and said reflective layer is formed of the same material as a material of ~~said~~ a gate electrode of said thin film transistor and formed on the same plane as a plane of said gate electrode.

3. (Withdrawn)

4. (Original) The reflection type liquid crystal display according to claim 1, wherein a color filter layer is disposed between said reflective layer and said transparent pixel electrode.

5. (Previously amended) The reflection type liquid crystal display according to claim 1, wherein a shielding layer is disposed on an area of at least one of said plurality of switching elements.

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6. (Currently amended) The reflection type liquid crystal display according to claim 2, wherein said thin film transistor comprises a the gate electrode electrically connected to a scanning line, a gate insulation film formed to cover said gate electrode, a semiconductor layer formed on said gate insulation film, a drain electrode electrically connected to a signal line, and a source electrode electrically connected to said transparent pixel electrode, and wherein said reflective layer is electrically separated from said gate electrode.

7. (Withdrawn)

8. (Previously amended) The reflection type liquid crystal display according to claim 1, wherein said reflective layer is formed of at least one of aluminum and an aluminum alloy.

9. (Original) The reflection type liquid crystal display according to claim 8, wherein said aluminum alloy is an alloy of aluminum and neodymium.

Claims 10, 11 (Withdrawn)

12. (Previously amended) The reflection type liquid crystal display according to claim 1, wherein at least one rough portion is formed below said reflective layer, and said reflective layer is formed to cover said at least one rough portion.

C² 13. (Original) The reflection type liquid crystal display according to claim 12, wherein said rough portion is formed of a material which is not deformed in a heating process performed later and which does not contain high density impurities adversely affecting the liquid crystal display.

14. (Original) The reflection type liquid crystal display according to claim 12, wherein said rough portion is formed by forming an insulation film and patterning the insulation film.

Claims 15-24 (Cancelled)

25. (Currently amended) A reflection type liquid crystal display, comprising:

a pair of substrates disposed opposite to each other via a liquid crystal layer;

a plurality of switching elements formed on one surface of said pair of substrates;

a reflective layer ~~constituted of a same material as a material constituting said switching element and~~ simultaneously formed during formation of said switching elements;

a transparent pixel electrode formed on said reflective layer via an insulation layer and connected to one electrode constituting one of said switching ~~element~~ elements;

wherein each of said plurality of switching ~~element~~ elements is a thin film transistor, and said reflective layer is formed of the same material as a material of a gate electrode of said thin film transistor and constituted on the same plane as a plane of said gate electrode; and

wherein a rough portion is formed below said reflective layer, and said reflective layer is formed to cover said rough portion.

26. (Currently amended) A reflection type liquid crystal display, comprising:

a pair of substrates disposed opposite to each other via a liquid crystal layer;

a plurality of switching elements formed on one surface of said pair of substrates;

a reflective layer ~~constituted of a same material as a material constituting said switching element~~ and simultaneously formed during formation of said switching elements;

02 a transparent pixel electrode formed on said reflective layer via an insulation layer and connected to one electrode constituting one of said switching element elements;

wherein said thin film transistor comprises a gate electrode electrically connected to a scanning line, a gate insulation film formed to cover said gate electrode, a semiconductor layer formed on said gate insulation film, a drain electrode electrically connected to a signal line, and a source electrode electrically connected to said transparent pixel electrode, and wherein said reflective layer is electrically separated from said gate electrode and is formed of a same material as a material of said gate electrode and formed on a same plane as a plane of said gate electrode; and

wherein a rough portion is formed below said reflective layer, and said reflective layer is formed to cover said rough portion.
